onsemi

Switch, N-Chanel

MMBF4093

Features

- This Device is Designed for Low Level Analog Switching Applications, Sample and Hold Circuits and Chopper Stabilized Amplifiers.
- Sourced from Process 51.
- This is a Pb–Free and a Halide Free Device

ABSOLUTE MAXIMUM RATINGS (Note 1), (Note 2)

(T_A = 25°C unless otherwise noted)

Symbol	Parameter	Value	Unit
V _{DG}	Drain-Gate Voltage	40	V
V _{GS}	Gate-Source Voltage	-40	V
I _{GF}	Forward Gate Current	50	mA
T _J , T _{STG}	Operating and Storage Junction Temperature Range	–55 to + 150	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. These ratings are based on a maximum junction temperature of 150°C.

2. These are steady-state limits. **onsemi** should be consulted on applications involving pulsed or low-duty cycle operations.

THERMAL CHARACTERISTICS ($T_A = 25^{\circ}C$ unless otherwise noted)

Symbol	Characteristic	Max	Unit
PD	Total Device Dissipation	350	mW
	Derate above 25°C	2.8	mW/°C
Reja	Thermal Resistance, Junction to Ambient (Note 3)	357	°C/W

3. Device mounted on FR–4 PCB 1.6" \times 1.6" \times 0.06".



SOT-23 CASE 318-08

Note: Source & Drain are interchangeable

MARKING DIAGRAM



61L = Specific Device Code

M = Date Code

= Pb-Free Package

(Note: Microdot may be in either location)

ORDERING INFORMATION

Device	Package	Shipping [†]
MMBF4093	SOT-23 (Pb-Free)	3000 / Tape and Real

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, <u>BRD8011/D</u>.

MMBF4093

ELECTRICAL CHARACTERISTICS ($T_A = 25^{\circ}C$ unless otherwise noted)

Symbol	Parameter	Test Conditions	Min	Max	Unit
OFF CHARAC	TERISTICS	-			
V _{(BR)GSS}	Gate-Source Breakdown Voltage	$I_G = 1 \ \mu A, V_{DS} = 0$	-40	-	V
$V_{GS}(off)$	Gate-Source Cut-Off Voltage	V _{DS} = 20 V, I _D = 1 nA	-1.0	-5.0	V
I _{DGO}	Drain-Gate Leakage Current			-200 -400	pA nA
I _D (off)	Drain Cutoff Leakage Current	V_{DS} = 20 V, V_{GS} = -6 V V_{DS} = 20 V, V_{GS} = -6 V, T_A = 150°C		200 400	pA nA
N CHARACT	ERISTICS	-			
I _{DSS}	Zero-Gate Voltage Drain Current (Note 4)	$V_{DS} = 20 \text{ V}, \text{ I}_{GS} = 0$	8	-	mA
V _{DS} (on)	Drain-Source On Voltage	$I_{D} = 2.5 \text{ mA}, V_{GS} = 0$	-	0.2	V
r _{DS} (on)	Drain-Source On Resistance	I _D = 1 mA, V _{GS} = 0	-	80	Ω
MALL SIGNA	AL CHARACTERISTICS				
r _{DS} (on)	Drain-Source On Resistance	$V_{DS} = V_{GS} = 0$, f = 1 kHz	-	80	Ω
C _{iss}	Input Capacitance	V_{DS} = 20 V, V_{GS} = 0 V, f = 1.0 MHz	-	16	pF
C _{rss}	Reverse Transfer Capacitance	V _{DS} = -20 V, f = 1.0 MHz	-	5	pF

SWITCHING CHARACTERISTICS

ſ	t _{On}	Turn-On Time	I _{D(on)} = 3.0 mA	-	60	ns
	t _{Off}	Turn–Off Time	$V_{GS(off)} = 3.0 V$	_	80	ns

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

4. Pulse Test: Pulse Width \leq 300 µs, Duty Cycle \leq 1%.

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SOT-23 (TO-236) 2.90x1.30x1.00 1.90P **CASE 318**

ISSUE AU

DATE 14 AUG 2024













XXX = Specific Device Code М = Date Code

= Pb-Free Package .

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.



MILLIMETERS						
DIM	MIN	NOM	МАХ			
А	0.89	1.00	1.11			
A1	0.01	0.06	0.10			
b	0.37	0.44	0.50			
с	0.08	0.14	0.20			
D	2.80	2.90	3.04			
E	1.20	1.30	1.40			
е	1.78	1.90	2.04			
L	0.30	0.43	0.55			
L1	0.35	0.54	0.69			
Ηe	2.10	2.40	2.64			
Т	0°		10°			

NOTES:

DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 2018. CONTROLLING DIMENSIONS: 1.

2. MILLIMETERS.

MILLIME IERS. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF THE 3.

BASE MATERIAL. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, 4. PROTRUSIONS, OR GATE BURRS.

RECOMMENDED MOUNTING FOOTPRINT

* For additional information on our Pb-Free strategy and soldering details, please download the onsemi Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

STYLES ON PAGE 2

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DATE 14 AUG 2024

STYLE 1 THRU 5: CANCELLED	STYLE 6: PIN 1. BASE 2. EMITTER 3. COLLECTOR	STYLE 7: PIN 1. EMITTER 2. BASE 3. COLLECTOR	STYLE 8: PIN 1. ANODE 2. NO CONNECTION 3. CATHODE	I	
STYLE 9:	STYLE 10:	STYLE 11:	STYLE 12:	STYLE 13:	STYLE 14:
PIN 1. ANODE	PIN 1. DRAIN	PIN 1. ANODE	PIN 1. CATHODE	PIN 1. SOURCE	PIN 1. CATHODE
2. ANODE	2. SOURCE	2. CATHODE	2. CATHODE	2. DRAIN	2. GATE
3. CATHODE	3. GATE	3. CATHODE-ANODE	3. ANODE	3. GATE	3. ANODE
STYLE 15:	STYLE 16:	STYLE 17:	STYLE 18:	STYLE 19:	STYLE 20:
PIN 1. GATE	PIN 1. ANODE	PIN 1. NO CONNECTION	PIN 1. NO CONNECTION	I PIN 1. CATHODE	PIN 1. CATHODE
2. CATHODE	2. CATHODE	2. ANODE	2. CATHODE	2. ANODE	2. ANODE
3. ANODE	3. CATHODE	3. CATHODE	3. ANODE	3. CATHODE-ANODE	3. GATE
STYLE 21:	STYLE 22:	STYLE 23:	STYLE 24:	STYLE 25:	STYLE 26:
PIN 1. GATE	PIN 1. RETURN	PIN 1. ANODE	PIN 1. GATE	PIN 1. ANODE	PIN 1. CATHODE
2. SOURCE	2. OUTPUT	2. ANODE	2. DRAIN	2. CATHODE	2. ANODE
3. DRAIN	3. INPUT	3. CATHODE	3. SOURCE	3. GATE	3. NO CONNECTION
STYLE 27: PIN 1. CATHODE 2. CATHODE 3. CATHODE	STYLE 28: PIN 1. ANODE 2. ANODE 3. ANODE				

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